

Anaren

RF Power

Model RFP-100200N4Z50-2

Aluminum Nitride Terminations

10 Watts, 50 Ω

Aluminum Nitride SMD Terminations



Features

- DC – 2.0 GHz
- 10 Watts
- Aluminum Nitride (AlN) Ceramic
- Surface Mountable
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

General Specifications

Resistive Element:	Thick film
Substrate:	Aluminum nitride ceramic
Terminals:	Tin/Lead, 90/10 over nickel

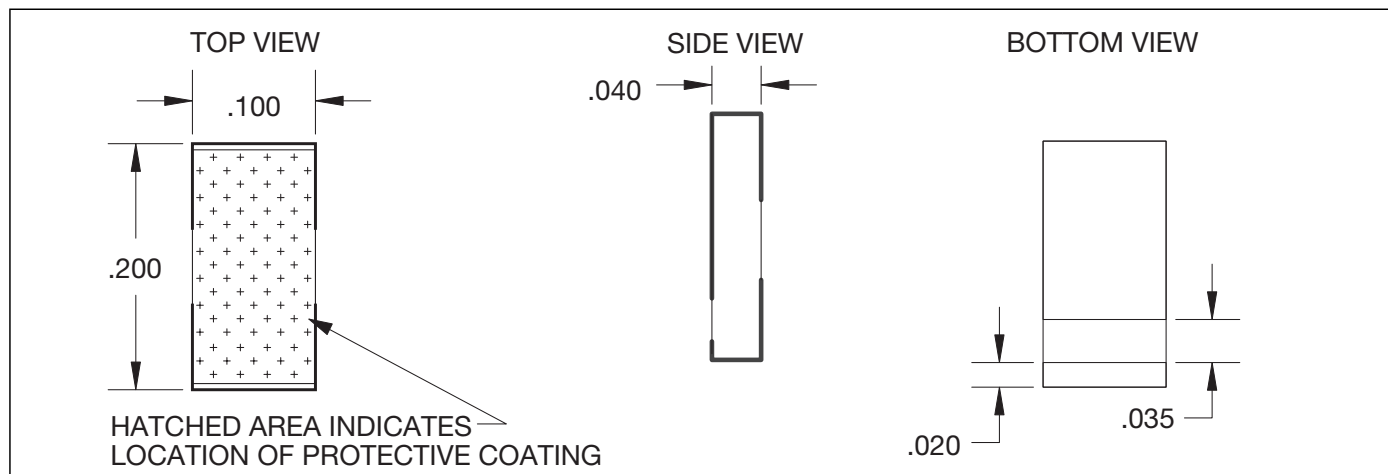
Electrical Specifications

Resistance Value:	50 ohms, $\pm 2\%$
Frequency Range:	DC - 2.0 GHz
Power:	10 Watts
V.S.W.R.:	1.25:1

Notes: Tolerance is ± 0.10 , unless otherwise specified. Operating temperature is -55°C to $+125^{\circ}\text{C}$ (see chart). Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions are in inches.

Specifications subject to change without notice.

Outline Drawing



VER. 12/5/01



Available on Tape and Reel for Pick and Place Manufacturing.

Sales Desk USA: Voice: (800) 544-2414 Fax: (315) 432-9121
Sales Desk Europe: Voice: (+44) 23 92 232392 Fax: (+44) 23 92 251369

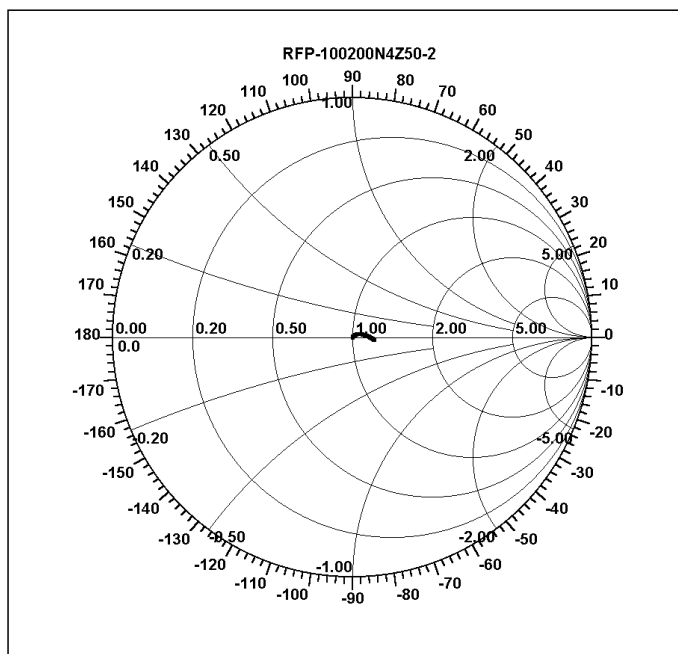
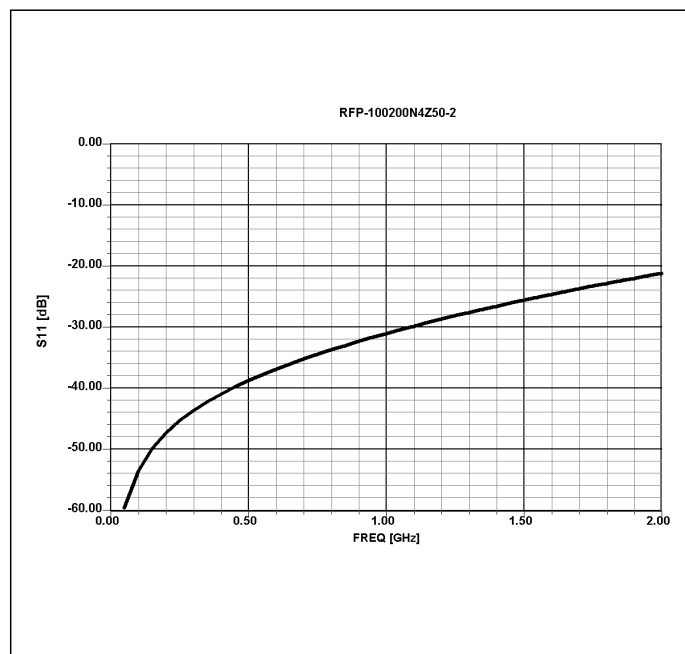
Anaren
What'll we think of next?™

Model RFP-100200N4Z50-2

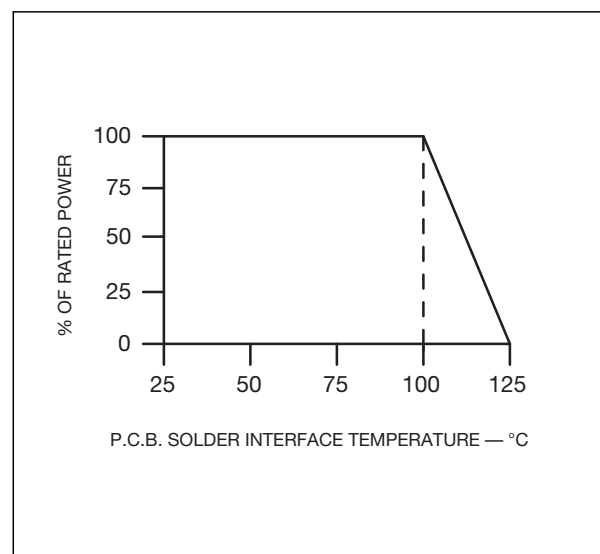
Anaren

RF Power

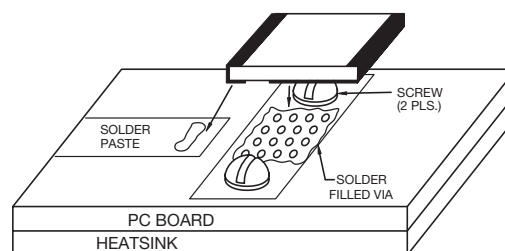
Typical Performance



Power Derating



Suggested Mounting Procedures



1. Solder part in place using 60/40 type solder with controlled temperature iron (700°F).
2. Drill thermal vias through PCB and fill with solder, such as 60/40 type.
3. To ensure good thermal connectivity to heat sink, drill and tap heatsink and mount PCB board to heat sink using screws.

Available on Tape and Reel for Pick and Place Manufacturing.

